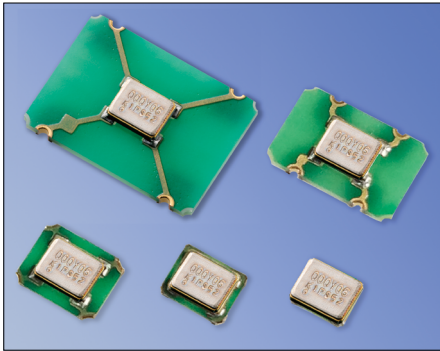




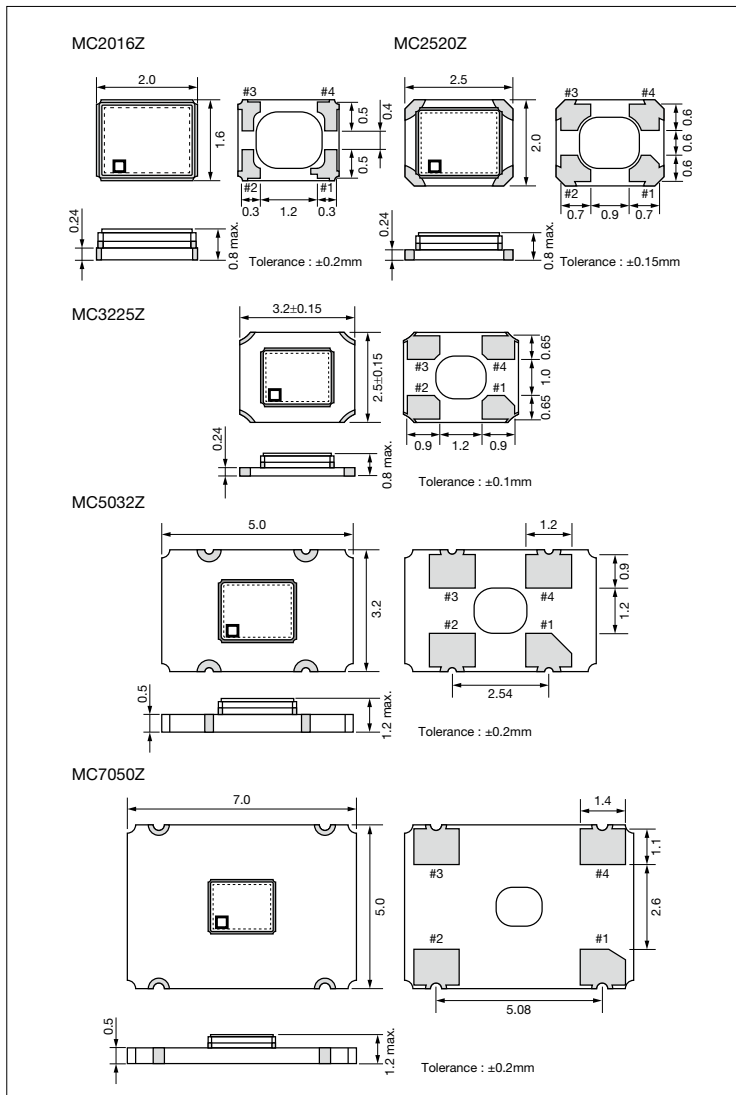
CMOS/ 1.8V, 2.5V, 3.3V / 2.0×1.6, 2.5×2.0, 3.2×2.5, 5.0×3.2, 7.0×5.0mm for Automotive



AEC-Q100/200 RoHS Compliant

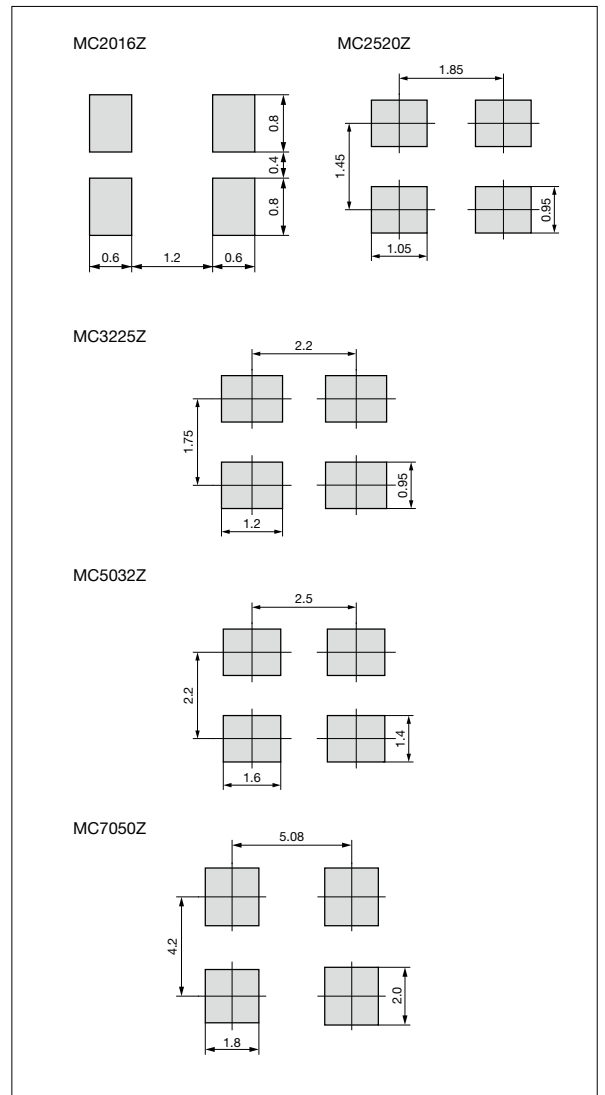
Dimensions

(Unit : mm)



Recommended Land Pattern

(Unit : mm)



Pad Connections	
#1	Stand-by Function
#2	Case GND
#3	Output
#4	Vcc

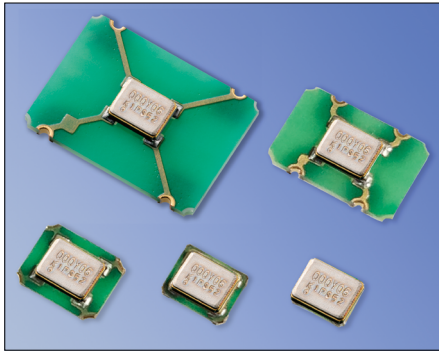
Stand-by Function	
Pad1	Pad3 (Output)
Open	Active
"H" Level	Active
"L" Level	High Z (No-Oscillation)

Clock Oscillators Surface Mount Type

Clock MC-Z-Series "X" type (STD, Short LT type)



CMOS/ 1.8V, 2.5V, 3.3V / 2.0×1.6, 2.5×2.0, 3.2×2.5, 5.0×3.2, 7.0×5.0mm for Automotive



AEC-Q100/200 RoHS Compliant

Features

- Frequency Range 0.5 to 170 MHz
- CMOS Output
- Short Lead Time
- Heat resistant up to +125°C

Applications

- Automotive

Table 5

Freq. Code	Tol. $\times 10^{-6}$	Operating Temperature Range (°C)	Note
G	± 50	-40 to +85	For additional stability, please contact us.
H	± 30		
J	± 25		
K	± 20	-40 to +105	
6	± 50		
5	± 30		
X	± 100	-40 to +125	
Z	± 50		
9	± 30		

How to Order

MC□□□□Z 25.0000 C 1 □ X SH
 ① ② ③ ④ ⑤ ⑥ ⑦

①Series

MC2016Z	2016 Size	MC2520Z	2520 Size
MC3225Z	3225 Size	MC5032Z	5032 Size
MC7050Z	7050 Size		

②Output Frequency (25.0000 : 25MHz)

③Output Type (C : CMOS)

④Supply Voltage

(1 : 1.8V/ 2.5V/ 3.3V Compatible)

⑤Frequency Tolerance (See Table 5)

⑥Symmetry/ INH Function

X	STD 45/ 55%
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⑦Individual Specification

(STD Specification is "SH".)

Packaging Tape&Reel

MC7050Z/ MC5032Z	1000 pcs./ reel
MC3225Z/ MC2520Z/ MC2016Z	2000 pcs./ reel

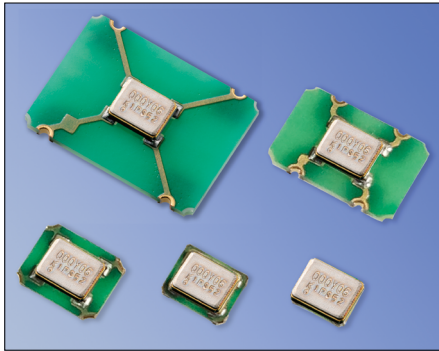
Specifications

Item	Symbol	Conditions	Min.	Max.	Unit	
Output Frequency Range	f_o		0.5	170	MHz	
Frequency Tolerance	f_{tol}	Initial tolerance, Operating temperature range, Rated power supply voltage change, Load change, Aging (1 year @25°C), Shock and vibration	See Table 5			
Storage Temperature Range	T_{stg}		-55	150	°C	
Operating Temperature Range	T_{use}		See Table 5			
Max. Supply Voltage	—		-0.3	4.5	V	
Supply Voltage	V_{cc}		1.71	3.63	V	
Current Consumption (Noload/ $1.71 < V_{cc} \leq 2.25$)	I_{cc}	$0.5 \leq f_o < 5\text{MHz}$	—	5.2	mA	
		$5 \leq f_o < 15\text{MHz}$	—	5.8		
		$15 \leq f_o < 30\text{MHz}$	—	6.2		
		$30 \leq f_o < 50\text{MHz}$	—	6.8		
		$50 \leq f_o \leq 60\text{MHz}$	—	6.8		
		$60 < f_o < 75\text{MHz}$	—	9		
		$75 \leq f_o < 105\text{MHz}$	—	10		
		$105 \leq f_o < 130\text{MHz}$	—	10.5		
		$130 \leq f_o < 160\text{MHz}$	—	11.5		
Current Consumption (Noload/ $2.25 < V_{cc} \leq 2.8$)	I_{cc}	$0.5 \leq f_o < 5\text{MHz}$	—	5.5	mA	
		$5 \leq f_o < 15\text{MHz}$	—	6		
		$15 \leq f_o < 30\text{MHz}$	—	6.5		
		$30 \leq f_o < 50\text{MHz}$	—	7.2		
		$50 \leq f_o \leq 60\text{MHz}$	—	7.4		
		$60 < f_o < 75\text{MHz}$	—	10		
		$75 \leq f_o < 105\text{MHz}$	—	11.5		
		$105 \leq f_o < 130\text{MHz}$	—	12.5		
		$130 \leq f_o < 160\text{MHz}$	—	14		
Current Consumption (Noload/ $2.8 < V_{cc} \leq 3.63$)	I_{cc}	$0.5 \leq f_o < 5\text{MHz}$	—	5.8	mA	
		$5 \leq f_o < 15\text{MHz}$	—	6.5		
		$15 \leq f_o < 30\text{MHz}$	—	7.3		
		$30 \leq f_o < 50\text{MHz}$	—	8		
		$50 \leq f_o \leq 60\text{MHz}$	—	8.5		
		$60 < f_o < 75\text{MHz}$	—	12.5		
		$75 \leq f_o < 105\text{MHz}$	—	14.5		
		$105 \leq f_o < 130\text{MHz}$	—	15.5		
		$130 \leq f_o < 160\text{MHz}$	—	18		
Stand-by Current	I_{std}		—	5	μA	
		Symmetry	@50% V_{cc}	45		55
Rise/ Fall Time (20% to 80% Output Level)	T_r / T_f	$0.5 \leq f_o \leq 60\text{MHz}$	Loaded/ $1.71 < V_{cc} \leq 2.25$	—	4	ns
			Loaded/ $2.25 < V_{cc} \leq 2.8$	—	3	
			Loaded/ $2.8 < V_{cc} \leq 3.63$	—	2.5	
		$60 < f_o \leq 170\text{MHz}$	Loaded/ $1.71 < V_{cc} \leq 2.25$	—	1.5	
			Loaded/ $2.25 < V_{cc} \leq 2.8$	—	1.3	
			Loaded/ $2.8 < V_{cc} \leq 3.63$	—	1	
Low Level Output Voltage	V_{OL}	$I_{OL} = 4\text{mA}$	—	10% V_{cc}	V	
High Level Output Voltage	V_{OH}	$I_{OH} = -4\text{mA}$	90% V_{cc}	—	V	
Output Load (CMOS)	L CMOS		—	15	pF	
Low Level Input Voltage	V_{IL}		—	30% V_{cc}	V	
High Level Input Voltage	V_{IH}		70% V_{cc}	—	V	
Disable Time	t_{dis}		—	200	ns	
Enable Time	t_{ena}		—	5	ms	
Start-up Time	t_{str}	@Minimum operating voltage to be 0 sec.	—	5	ms	

All electrical characteristics are defined at the maximum load and operating temperature range.



CMOS/ 1.8V, 2.5V, 3.3V / 2.0×1.6, 2.5×2.0, 3.2×2.5, 5.0×3.2, 7.0×5.0mm for Automotive



AEC-Q100/200 RoHS Compliant

Features

- Frequency Range 24 to 72 MHz
- CMOS Output
- Low Jitter
- Heat resistant up to +125°C

Applications

- Automotive (Radar, Camera, Network)

Table 7

Freq. Code	Tol. $\times 10^{-6}$	Operating Temperature Range (°C)	Note
G	± 50	-40 to +85	For additional stability, please contact us.
H	± 30		
J	± 25		
K	± 20		
6	± 50	-40 to +105	
5	± 30		
X	± 100	-40 to +125	
Z	± 50		
9	± 30		

How to Order

MC□□□□Z 25.0000 C 1 □ Y SH
① ② ③ ④ ⑤ ⑥ ⑦

①Series

MC2016Z	2016 Size	MC2520Z	2520 Size
MC3225Z	3225 Size	MC5032Z	5032 Size
MC7050Z	7050 Size		

②Output Frequency (25.0000 : 25MHz)

③Output Type (C : CMOS)

④Supply Voltage

(1 : 1.8V/ 2.5V/ 3.3V Compatible)

⑤Frequency Tolerance (See Table 7)

⑥Symmetry/ INH Function

Y	STD/ Low Jitter 45/ 55%
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⑦Individual Specification

(STD Specification is "SH".)

Packaging Tape&Reel

MC7050Z/ MC5032Z	1000 pcs./ reel
MC3225Z/ MC2520Z/ MC2016Z	2000 pcs./ reel

Specifications

Item	Symbol	Conditions	Min.	Max.	Unit	
Output Frequency Range	fo		24	72	MHz	
Frequency Tolerance	f _{tol}	Initial tolerance, Operating temperature range, Rated power supply voltage change, Load change, Aging (1 year @25°C), Shock and vibration	See Table 7			
Storage Temperature Range	T _{stg}		-55	150	°C	
Operating Temperature Range	T _{use}		See Table 7			
Max. Supply Voltage	—		-0.3	4.5	V	
Supply Voltage	V _{cc}		1.71	3.63	V	
Current Consumption (Noload/ 1.71≤V _{cc} ≤2.25)	I _{cc}	24≤fo<30MHz	—	2.7	mA	
		30≤fo<50MHz	—	3.3		
		50≤fo≤60MHz	—	3.7		
		60<fo<72MHz	—	4		
Current Consumption (Noload/ 2.25<V _{cc} ≤2.8)	I _{cc}	24≤fo<30MHz	—	3.5		
		30≤fo<50MHz	—	4		
		50≤fo≤60MHz	—	4.3		
		60<fo<72MHz	—	4.8		
Current Consumption (Noload/ 2.8<V _{cc} ≤3.63)	I _{cc}	24≤fo<30MHz	—	4		
		30≤fo<50MHz	—	5		
		50≤fo≤60MHz	—	5.5		
		60<fo<72MHz	—	6		
Stand-by Current	I _{std}		—	5	μA	
Symmetry	SYM	@50% V _{cc}	24≤fo≤40MHz	40	55	%
			40<fo≤72MHz	45	55	
Rise/ Fall Time (20% to 80% Output Level)	Tr/ Tf	Loaded/ 1.71≤V _{cc} ≤2.25	—	4	ns	
		Loaded/ 2.25<V _{cc} ≤2.8	—	3.2		
		Loaded/ 2.8<V _{cc} ≤3.63	—	2.7		
Low Level Output Voltage	V _{OL}	I _{OL} = 4mA	—	10% V _{cc}	V	
High Level Output Voltage	V _{OH}	I _{OH} = -4mA	90% V _{cc}	—	V	
Output Load (CMOS)	L _{CMOS}		—	15	pF	
Low Level Input Voltage	V _{IL}		—	30% V _{cc}	V	
High Level Input Voltage	V _{IH}		70% V _{cc}	—	V	
Disable Time	t _{dis}		—	200	ns	
Enable Time	t _{ena}		—	10	ms	
Start-up Time	t _{str}	@Minimum operating voltage to be 0 sec.	—	10	ms	
1 Sigma Jitter	J _{Sigma}	Measured with Wavecrest SIA-3000	—	5	ps	
Peak to Peak Jitter	J _{PK_PK}		—	50		
Phase Jitter	—	@50MHz V _{cc} = 3.3V	BW : 12kHz to 20MHz		1	ps

All electrical characteristics are defined at the maximum load and operating temperature range.